## ESH2B-M3, ESH2C-M3, ESH2D-M3

Vishay General Semiconductor

COMPLIANT

HALOGEN

FREE

### **Surface-Mount Ultrafast Plastic Rectifier**



**SMB (DO-214AA)** 

Cathode O Anode

#### **LINKS TO ADDITIONAL RESOURCES**



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2.0 A				
V <sub>RRM</sub> 100 V, 150 V, 200					
t <sub>rr</sub>	25 ns				
V <sub>F</sub>	0.93 V				
T <sub>J</sub> max.	175 °C				
Package	SMB (DO-214AA)				
Circuit configuration	Single				

#### **FEATURES**

- Glass passivated pellet chip junction
- · Ideal for automated placement
- · Ultrafast recovery times for high efficiency
- Low forward voltage, low power loss
- · High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converter and inverter for both consumer.

#### **MECHANICAL DATA**

Case: SMB (DO-214AA)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test **Polarity:** color band denotes cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	ESH2B	ESH2C	ESH2D	UNIT
Device marking code		EHB	EHC	EHD	
Maximum repetitive peak reverse voltage	$V_{RRM}$	100	150	200	V
Maximum RMS voltage	V <sub>RMS</sub>	70	105	140	V
Maximum DC blocking voltage	V <sub>DC</sub>	100	150	200	V
Maximum average forward rectified current (fig. 1)	I <sub>F(AV)</sub>	2.0			Α
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	60			А
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +175			°C



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT	
Maximum instantaneous forward voltage	I <sub>F</sub> = 2 A		V <sub>F</sub> <sup>(1)</sup>	0.93	V	
Maximum DC reverse current		T <sub>A</sub> = 25 °C	1	2.0	μΑ	
at rated DC blocking voltage		T <sub>A</sub> = 125 °C	I <sub>R</sub>	50		
Maximum reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		t <sub>rr</sub>	25	ns	
Typical reverse recovery time	$I_F = 2 A, V_R = 30 V,$	T <sub>J</sub> = 25 °C	- t <sub>rr</sub>	35	ns	
	$dI/dt = 50 A/\mu s, I_{rr} = 10 \% I_{RM}$	T <sub>J</sub> = 100 °C		55		
Typical stored charge	$I_F = 2 A, V_R = 30 V,$	T <sub>J</sub> = 25 °C	Q <sub>rr</sub>	20	nC	
	$dI/dt = 50 A/\mu s$ , $I_{rr} = 10 \% I_{RM}$	T <sub>J</sub> = 100 °C		35		
Typical junction capacitance	4.0 V, 1 MHz		CJ	30	pF	

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	ESH2B ESH2C ESH2D UNIT				
Typical thormal registance	R <sub>0JA</sub> (1)	65			°C/W	
Typical thermal resistance	R <sub>θJL</sub> <sup>(1)</sup>		20	_	C/VV	

#### Note

(1) Units mounted on PCB with 8.0 mm x 8.0 mm land areas

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ESH2D-M3/52T	0.096	52T	750	7" diameter plastic tape and reel		
ESH2D-M3/5BT	0.096	5BT	3200	13" diameter plastic tape and reel		



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### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

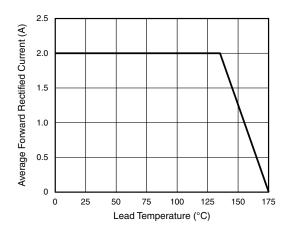


Fig. 1 - Maximum Forward Current Derating Curve

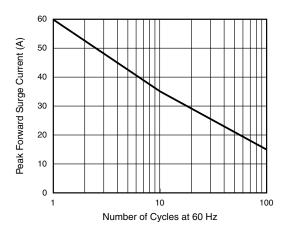


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

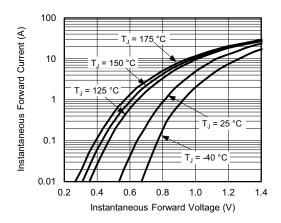


Fig. 3 - Typical Instantaneous Forward Characteristics

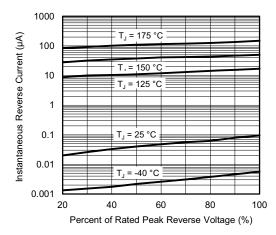


Fig. 4 - Typical Reverse Leakage Characteristics

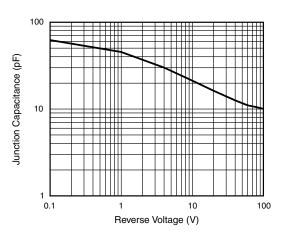


Fig. 5 - Typical Junction Capacitance

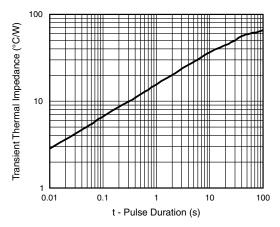


Fig. 6 - Typical Transient Thermal Impedance

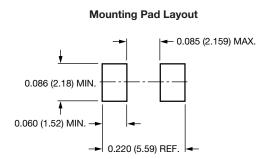
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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

# 0.086 (2.20) 0.077 (1.95) 0.180 (4.57) 0.160 (4.06) 0.096 (2.44) 0.084 (2.13) 0.096 (2.44) 0.084 (2.13) 0.096 (0.152) 0.096 (0.152)

0.205 (5.21)





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